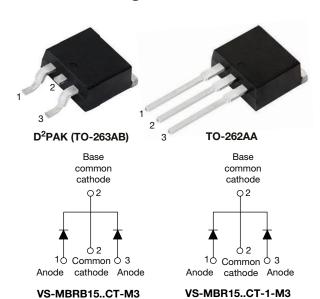
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 7.5 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 7.5 A				
V _R	35 V, 45 V				
V _F at I _F	0.57 V				
I _{RM} max.	15 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	7 mJ				
Package	D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

FEATURES

- 150 °C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBR(B)15... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	15	А				
V _{RRM}		35/45	V				
I _{FSM}	$t_p = 5 \mu s sine$	690	А				
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V				
TJ		-65 to +150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRB1535CT-M3 VS-MBR1535CT-1-M3	VS-MBRB1545CT-M3 VS-MBR1545CT-1-M3	UNITS		
Maximum DC reverse voltage	V_{R}	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	45	V		



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum average per leg		T _ 121 °C roto	od V	7.5			
forward current per device	$\frac{S}{e}$ $I_{F(AV)}$ $T_C = 131$ °C, rated V_R		$I_C = 131^{\circ}$ C, rated V_R				
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	690 A			
non-repetitive surge	I _{FSM}	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150			
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 3.5$ mH		7	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _L maximum V _A = 1.5 x V _B typical		2	А		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T _J = 25 °C	0.84			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T _{.1} = 125 °C	0.57	V		
		15 A	1j = 125 C	0.72			
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA		
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	15			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	ige 100 kHz to 1 MHz), 25 °C	400	pF		
Typical series inductance	L _S	Measured from top of terr	minal to mounting plane	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range		T_J		-65 to +150	°C	
Maximum storage temperature range		T _{Stg}		-65 to +175	C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	3.0		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	60		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf ⋅ in)	
Mandring aloring			Case style D ² PAK (TO-263AB)	MBRB1	545CT	
Marking device			Case style TO-262AA	MBR15	45CT-1	

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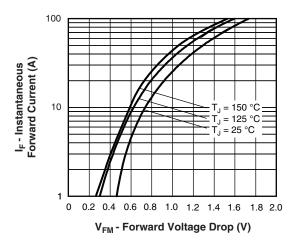


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

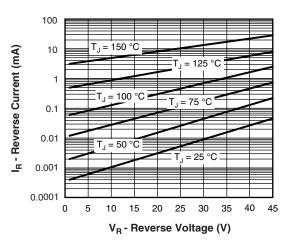


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

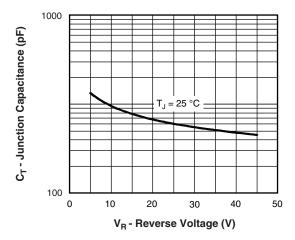


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

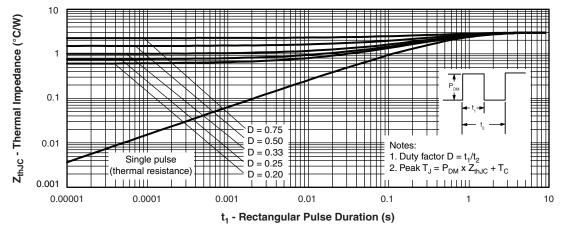


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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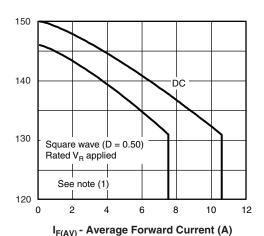


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

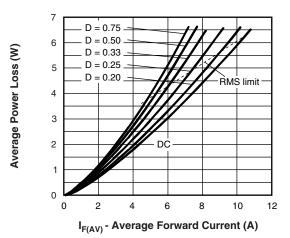


Fig. 6 - Forward Power Loss Characteristics

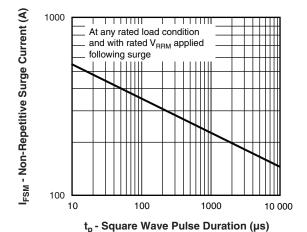


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

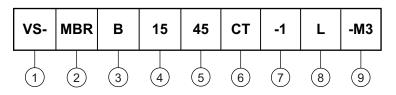
Allowable Case Temperature (°C)

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Essential part number

• B = D^2PAK (TO-263AB) None = -1

• None = TO-262AA

Current rating (15 = 15 A)

35 = 35 VVoltage ratings -45 = 45 V

CT = essential part number

• None = D²PAK = B • -1 = TO-262AA None

8 • None = tube

• L = tape and reel (left oriented - for D²PAK (TO-263AB) only)

• R = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-MBRB1535CTL-M3	800	13" diameter plastic tape and reel
VS-MBRB1535CT-M3	50	Antistatic plastic tubes
VS-MBRB1535CTR-M3	800	13" diameter plastic tape and reel
VS-MBRB1545CTL-M3	800	13" diameter plastic tape and reel
VS-MBRB1545CT-M3	50	Antistatic plastic tubes
VS-MBRB1545CTR-M3	800	13" diameter plastic tape and reel
VS-MBR1535CT-1-M3	50	Antistatic plastic tubes
VS-MBR1545CT-1-M3	50	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				
SPICE model		www.vishay.com/doc?95294				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches

Modified JEDEC® outline TO-262







⊕ 0.010 **M** A**M** B

Lead assignments



Diodes 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	IETERS	INC	HES	NOTES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100) BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
 (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- Controlling dimension: inches
- Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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